

MN3208

2048-STAGE LOW VOLTAGE OPERATION LOW NOISE BBD

General description

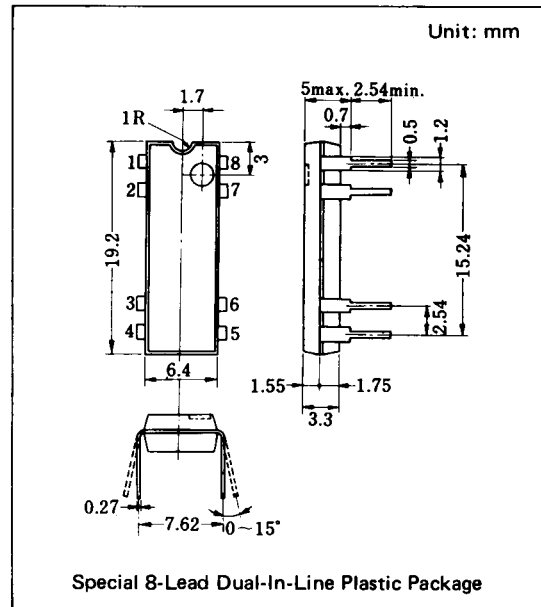
The MN3208 is a 2048-stage low voltage operation ($V_{DD} = 5V$) low noise BBD that provides a signal delay of up to 102.4ms and is suitable as a device for generation of reverberation effect of audio equipment such as stereo equipments.

Features

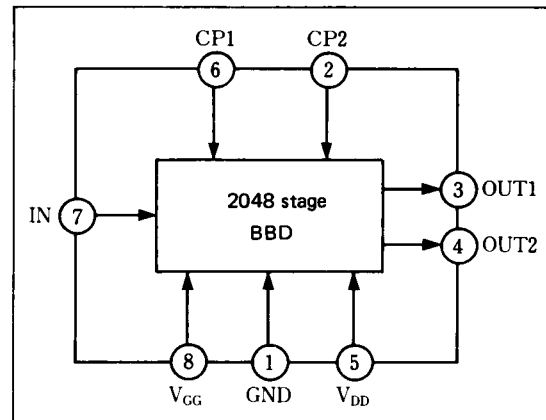
- Variable delay of audio signals: 10.24ms ~ 102.4ms.
- Wide supply voltage: 4 ~ 10V.
- Clock component cancellation capability.
- No insertion loss: $L_i = 0dB$ typ.
- Wide dynamic range: $S/N = 71dB$ typ.
- Low distortion: $THD = 0.5\%$ typ. ($V_i = 0.25V_{rms}$)
- N-channel silicon gate process.
- Special 8-lead dual-in-line plastic package.

Applications

- Reverberation and echo effects of audio equipment such as radio cassette recorder, car radio, portable radio, portable stereo, echo microphone and pre-taped musical accompaniment (Karaoke), etc.
- Sound effect in electronic musical instruments.
- Variable or fixed delay of analog signals.
- Telephone time compression and delay line for voice communication system.



Block Diagram



Quick Reference Data

Item	Symbol	Value	Unit
Supply Voltage	V_{DD}, V_{GG}	+ 5, $\frac{1}{3}V_{DD}$	V
Signal Delay Time	t_D	10.24~102.4	ms
Total Harmonic Distortion	THD	0.5	%
Signal to Noise Ratio	S/N	71	dB

■ Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Terminal Voltage	V _{DD} , V _{GG} , V _{CP} , V _I	-0.3~+11	V
Output Voltage	V _O	-0.3~+11	V
Operating Temperature	T _{opr}	-20~+60	°C
Storage Temperature	T _{stg}	-55~+125	°C

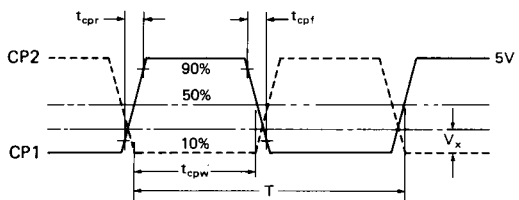
■ Operating Condition (Ta = 25°C)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Drain Supply Voltage	V _{DD}		+4	+5	+10	V
Gate Supply Voltage	V _{GG}			$\frac{14}{15}V_{DD}$		V
Clock Voltage "H" Level	V _{CPH}			V _{DD}		V
Clock Voltage "L" Level	V _{CPL}		0		+1	V
Clock Frequency	f _{CP}		10		100	kHz
Clock Pulse Width *1	t _{CPW}				0.5T *2	
Clock Rise Time *1	t _{CPr}				500	ns
Clock Fall Time *1	t _{CPf}				500	ns
Clock Input Capacitance	C _{CP}				1400	pF
Clock Cross Point *1	V _X		0		0.3V _{CPH}	V

■ Electrical Characteristics (Ta=25°C, V_{DD}=V_{CPH}=+5V, V_{CPL}=0V, V_{GG}= $\frac{14}{15}V_{DD}$, R_L=100kΩ)

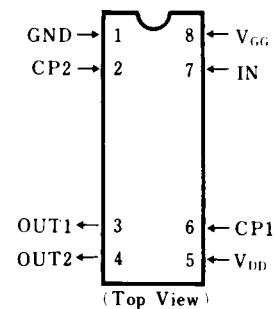
Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Signal Delay Time	t _D		10.24		102.4	ms
Input Signal Frequency	f _i	f _{CP} = 40kHz, 3dB down (0dB at f _i = 1kHz)	9			kHz
Input Signal Swing	V _i	THD=2.5%	0.36			V _{rms}
Insertion Loss	L _i	f _{CP} =40kHz, f _i =1kHz	-4	0	4	dB
Total Harmonic Distortion	THD	f _{CP} =40kHz, f _i =1kHz, V _i =0.25V _{rms}		0.5	2.5	%
Noise	V _{no}	f _{CP} = 100kHz Weighted by "A" curve			0.3	mV _{rms}
Signal To Noise Ratio	S/N			71		dB

*1 Clock Pulse Waveforms

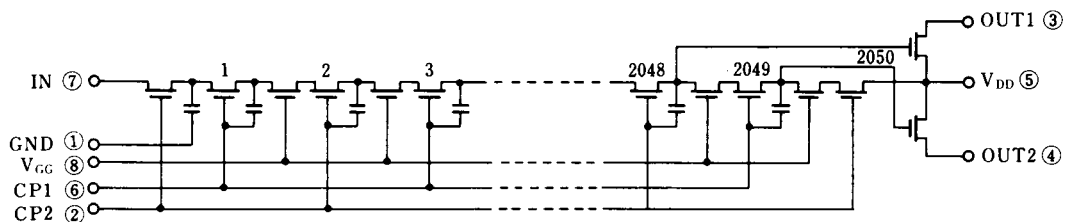


*2 T = 1/f_{CP} (Clock Period)

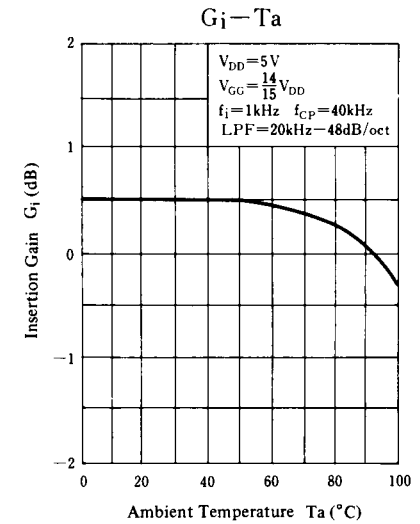
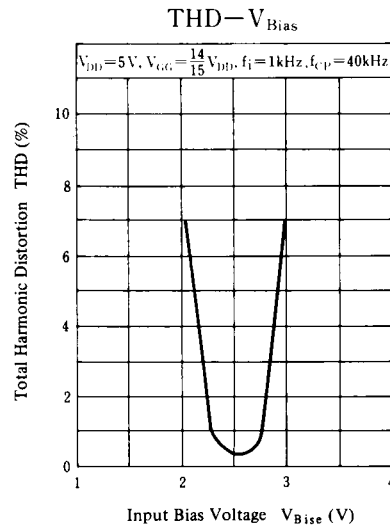
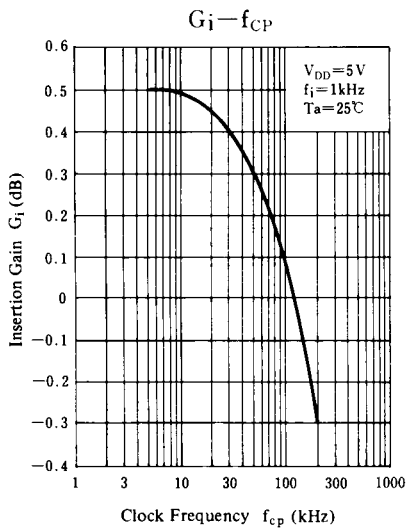
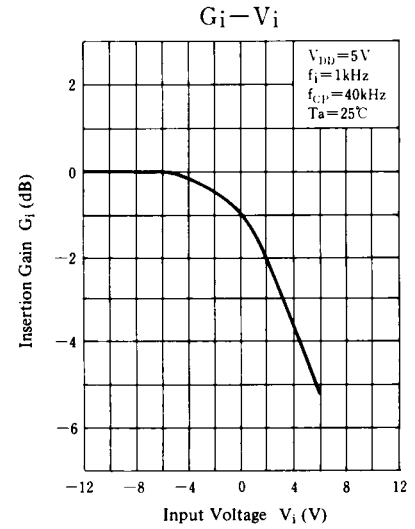
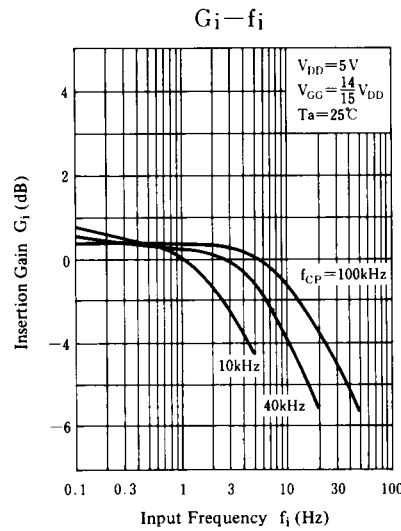
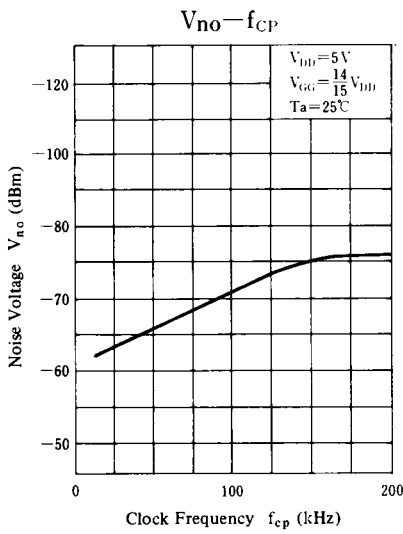
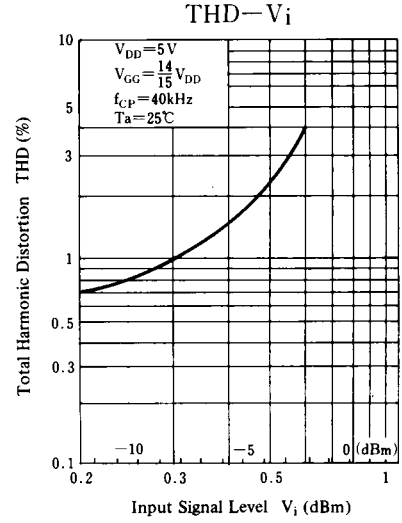
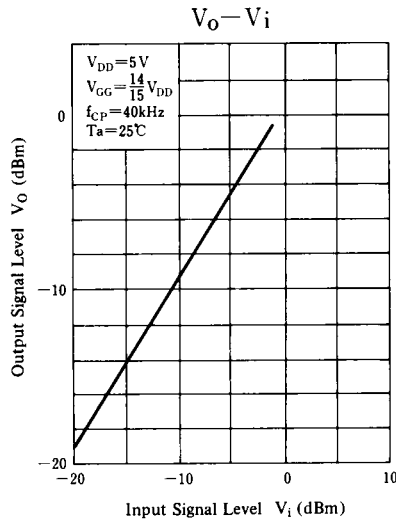
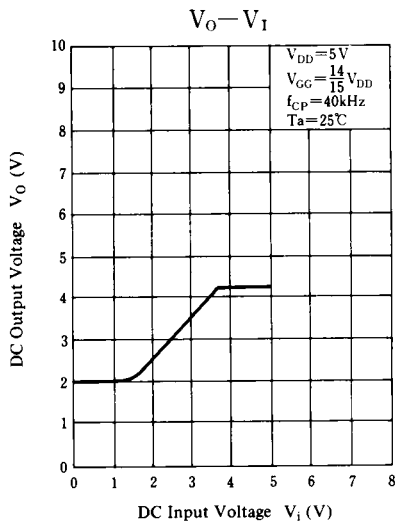
■ Terminal Assignments

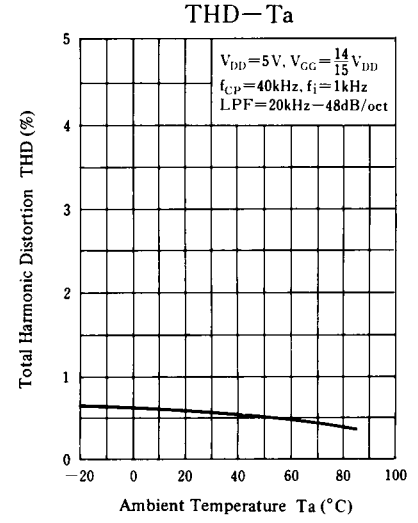
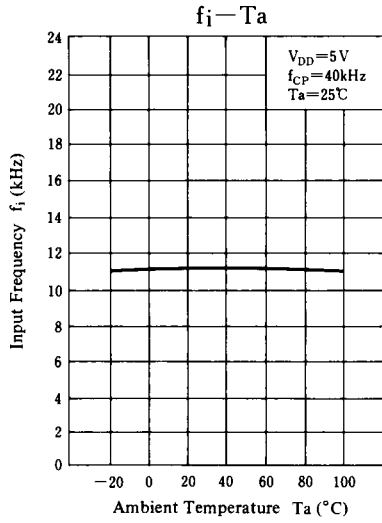
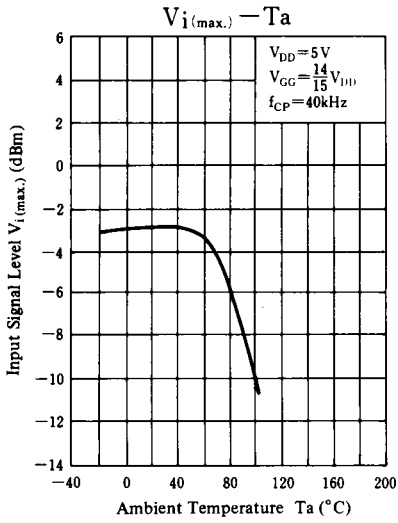


■ Circuit Diagram

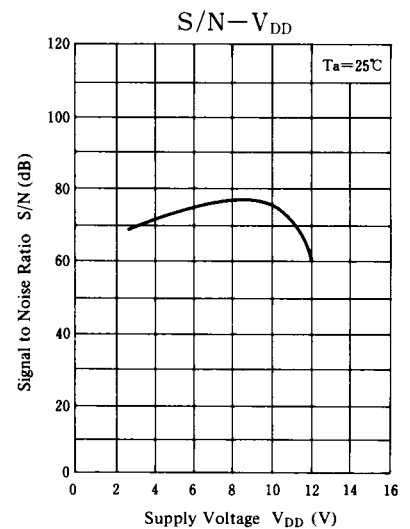
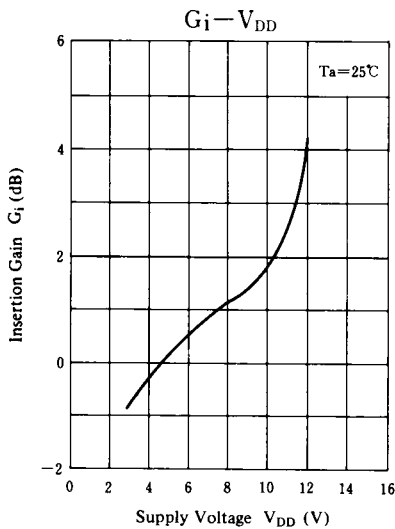
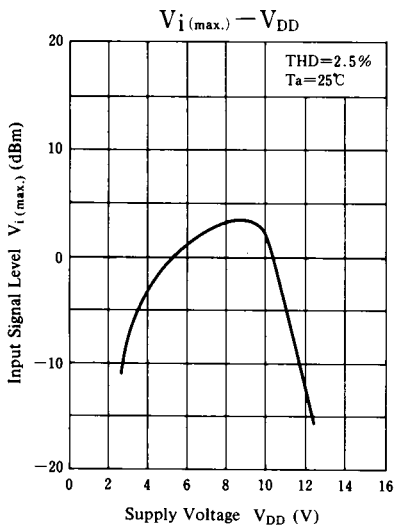
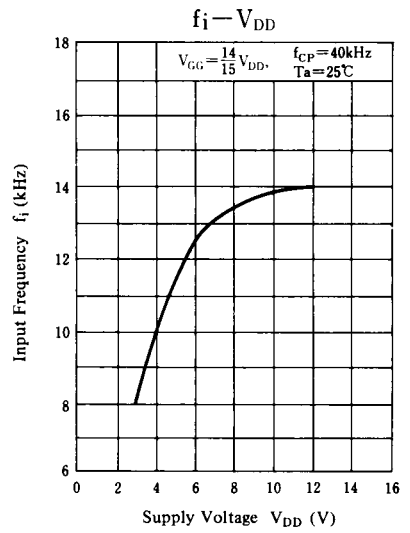
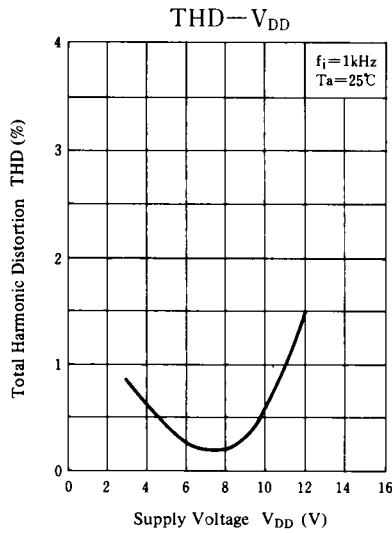
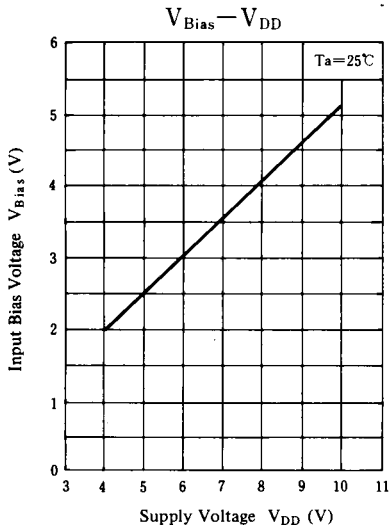


■ Typical Electrical Characteristic Curves

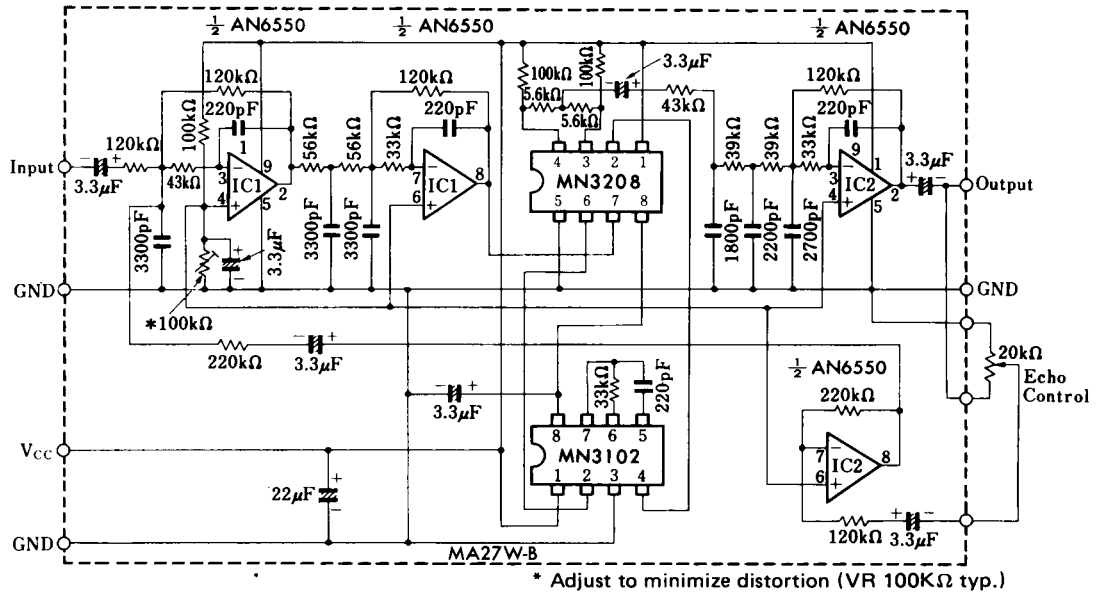




Supply Voltage Characteristics



■ Application Circuit



Reverberation Effect Generation Circuit (Signal Delay Over 100msec.)